

NOTICE OF REVISION (NOR)		1. DATE (YYMMDD) 94-09-20	Form Approved OMB No. 0704-0188
This revision described below has been authorized for the document listed.			
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			3. DODAAC
4. ORIGINATOR	b. ADDRESS (Street, City, State, Zip Code) Defense Electronics Supply Center 1507 Wilmington Pike Dayton, OH 45444-5270	5. CAGE CODE 67268	6. NOR NO. 5962-R279-94
a. TYPED NAME (First, Middle Initial, Last)		7. CAGE CODE 67268	8. DOCUMENT NO. 5962-88518
9. TITLE OF DOCUMENT MICROCIRCUIT, MEMORY, DIGITAL, CMOS, 512 X 8 REGISTERED PROM, MONOLITHIC SILICON		10. REVISION LETTER	
		a. CURRENT B	b. NEW C
11. ECP NO. N/A			
12. CONFIGURATION ITEM (OR SYSTEM) TO WHICH ECP APPLIES All			
13. DESCRIPTION OF REVISION Sheet 1: Revisions ltr column; add "C". Revisions description column; add "Changes in accordance with NOR 5962-R279-94". Revisions date column; add "94-09-20". Rev status of sheets; For sheets 8 and 9; add "C". Sheet 8: FIGURE 2. <u>Truth table</u> . Delete pin function \bar{E} (between CP and \bar{CLR}) and substitute \bar{E}_S . Sheet 9: FIGURE 5. <u>Switching waveforms</u> . Add NOTE: Transition is measured at steady state high level -500 mV or steady state low level +500 mV on the output from the 1.5 V level on the input with loads shown on figure 4; $C_L = 5$ pF. Sheets 1, 8 and 9: Revision level block; add "C".			
14. THIS SECTION FOR GOVERNMENT USE ONLY			
a. (X one)	<input checked="" type="checkbox"/>	(1) Existing document supplemented by the NOR may be used in manufacture.	
	<input type="checkbox"/>	(2) Revised document must be received before manufacturer may incorporate this change.	
	<input type="checkbox"/>	(3) Custodian of master document shall make above revision and furnish revised document.	
b. ACTIVITY AUTHORIZED TO APPROVE CHANGE FOR GOVERNMENT DESC-ELDS		c. TYPED NAME (First, Middle Initial, Last) Michael A. Frye	
d. TITLE Chief, Microelectronics Branch	e. SIGNATURE Michael A. Frye		f. DATE SIGNED (YYMMDD) 94-09-20
15a. ACTIVITY ACCOMPLISHING REVISION DESC-ELDS	b. REVISION COMPLETED (Signature) Gary L. Gross		c. DATE SIGNED (YYMMDD) 94-09-20

REVISIONS

LTR	DESCRIPTION	DATE (YR-MO-DA)	APPROVED
A	Changes in accordance with NOR 5962-R028-94.	93-11-05	M. A. Frye
B	Updated boilerplate. Added device types 04-07. Removed programming requirements from drawing. Editorial changes throughout.	94-04-15	M. A. Frye

REV																				
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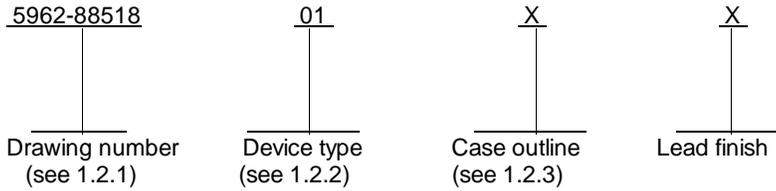
REV STATUS OF SHEETS	REV	B	B	B	B	B	B	B	B	B	B	B	B				
	SHEET	1	2	3	4	5	6	7	8	9	10	11					

<p align="center">STANDARDIZED MILITARY DRAWING</p> <p align="center">THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE</p> <p align="center">AMSC N/A</p>	PMIC N/A	PREPARED BY Monica L. Poelking	DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		
		CHECKED BY Ray Monnin			
		APPROVED BY Michael A. Frye	MICROCIRCUIT, MEMORY, DIGITAL, CMOS 512 X 8 REGISTERED PROM, MONOLITHIC SILICON		
		DRAWING APPROVAL DATE 88-07-11			
		REVISION LEVEL B			
SHEET 1 OF 11					

1. SCOPE

1.1 Scope. This drawing describes device requirements for class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".

1.2 Part or Identifying Number (PIN). The complete PIN shall be as shown in the following example:



1.2.1 Device type(s). The device type(s) shall identify the circuit function as follows:

<u>Device type</u>	<u>Generic number 1/</u>	<u>Circuit function</u>	<u>Access time</u>
01		512 X 8-bit registered PROM	30
02		512 X 8-bit registered PROM	35
03		512 X 8-bit registered PROM	40
04		512 X 8-bit registered PROM	30
05		512 X 8-bit registered PROM	35
06		512 X 8-bit registered PROM	40
07		512 X 8-bit registered PROM	25

1.2.2 Case outline(s). The case outline(s) shall be as designated in MIL-STD-1835 and as follows:

<u>Outline letter</u>	<u>Descriptive designator</u>	<u>Terminals</u>	<u>Package style</u>
L	CDIP4-T24 or GDIP3-T24	24	Dual-in-line
3	CQCC1-N28	28	Square chip carrier

1.2.3 Lead finish. The lead finish shall be as specified in MIL-STD-883 (see 3.1 herein). Finish letter "X" shall not be marked on the microcircuit or its packaging. The "X" designation is for use in specifications when lead finishes A, B, and C are considered acceptable and interchangeable without preference.

1.3 Absolute maximum ratings. 2/

Supply voltage range to ground potential (V_{CC})	-0.5 V dc to +7.0 V dc
DC voltage range applied to the outputs in the high Z state	-0.5 V dc to +7.0 V dc
DC input voltage	-3.0 V dc to +7.0 V dc
Maximum power dissipation	1.0 W 3/
Lead temperature (soldering, 10 seconds)	+300° C
Thermal resistance, junction-to-case (θ_{JC})	See MIL-STD-1835
Junction temperature (T_J)	+150° C 4/
Storage temperature range (T_{STG})	-65° C to +150° C
Temperature under bias	-55° C to +125° C
Data retention	10 years, minimum

1.4 Recommended operating conditions.

Supply voltage range (V_{CC})	+4.5 V dc minimum to +5.5 V dc maximum
Input high voltage range (V_{IH})	+2.0 V dc
Input low voltage range (V_{IL})	+0.8 V dc
Case operating temperature range (T_C)	-55° C to +125° C

1/ Generic numbers are listed on the Standardized Military Drawing Source Approval Bulletin and will also be listed in MIL-BUL-103.

2/ Unless otherwise specified, all voltages are referenced to ground.

3/ Must withstand the added P_D due to short circuit test; e.g., I_{OS} .

4/ Maximum junction temperature may be increased to +175° C during burn-in and steady state life tests.

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		REVISION LEVEL B	SHEET 2

2. APPLICABLE DOCUMENTS

2.1 Government specification, standards, bulletin, and handbook. Unless otherwise specified, the following specification, standards, bulletin, and handbook of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-I-38535 - Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

MILITARY

MIL-STD-883 - Test Methods and Procedures for Microelectronics.
 MIL-STD-1835 - Microcircuit Case Outlines.

BULLETIN

MILITARY

MIL-BUL-103 - List of Standardized Military Drawings (SMD's).

(Copies of the specifications, standards, bulletin, and handbook required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein. Product built to this drawing that is produced by a Qualified Manufacturer Listing (QML) certified and qualified manufacturer or a manufacturer who has been granted transitional certification to MIL-I-38535 may be processed as QML product in accordance with the manufacturers approved program plan and qualifying activity approval in accordance with MIL-I-38535. This QML flow as documented in the Quality Management (QM) plan may make modifications to the requirements herein. These modifications shall not affect form, fit, or function of the device. These modifications shall not affect the PIN as described herein. A "Q" or "QML" certification mark in accordance with MIL-I-38535 is required to identify when the QML flow option is used.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-STD-883 (see 3.1 herein) and herein.

3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.

3.2.2 Truth table. The truth table shall be as specified on figure 2.

3.2.2.1 Unprogrammed devices. The truth table for unprogrammed devices for contracts involving no altered item drawing shall be as specified on figure 2. When required in groups A, B, C, or D (see 4.4), the devices shall be programmed by the manufacturer prior to test with a checkerboard pattern or equivalent (a minimum of 50 percent of the total number of bits programmed) or to any altered item drawing pattern which includes at least 25 percent of the total number of bits programmed.

3.2.2.2 Programmed devices. The truth table for programmed devices shall be as specified by an attached altered item drawing.

3.2.3 Logic diagram(s). The logic diagram shall be as specified on figure 3.

3.2.4 AC test loads and waveforms. The ac test loads and waveforms shall be as specified on figure 4.

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3.2.5 Switching waveforms. The switching waveforms shall be as specified on figure 5.

3.2.6 Case outline(s). The case outline(s) shall be in accordance with 1.2.2 herein.

3.3 Electrical performance characteristics. Unless otherwise specified herein, the electrical performance characteristics are as specified in table I and shall apply over the full (case or ambient) operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.

3.5 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103 (see 6.6 herein).

3.6 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.6 herein). The certificate of compliance submitted to DESC-EC prior to listing as an approved source of supply shall affirm that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.

3.7 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change. Notification of change to DESC-EC shall be required in accordance with MIL-STD-883 (see 3.1 herein).

3.9 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.10 Data retention. A data retention stress test shall be completed as part of the vendor's reliability monitors. This test shall be done initially and after any design or process change which may affect data retention. The methods and procedures may be vendor specific, but will guarantee the number of years listed in section 1.3 herein over the full military temperature range. The vendor's procedure shall be kept under document control and shall be made available upon request.

4. QUALITY ASSURANCE PROVISIONS

4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with MIL-STD-883 (see 3.1 herein).

4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:

a. Burn-in test, method 1015 of MIL-STD-883.

(1) Test condition C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.

(2) $T_A = +125^\circ\text{C}$, minimum.

b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55° C ≤ T _C ≤ +125° C 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Output voltage high	V _{OH}	V _{CC} = 4.5 V, I _{OH} = -4 mA V _{IH} = 2.0 V, V _{IL} = 0.8 V	1, 2, 3	ALL	2.4		V
Output voltage low	V _{OL}	V _{CC} = 4.5 V, I _{OL} = 16 mA V _{IH} = 2.0 V, V _{IL} = 0.8 V	1, 2, 3	ALL		0.4	V
Input leakage current	I _{IX}	V _{CC} = 5.5 V V _{IN} = 5.5 V and GND.	1, 2, 3	All	-10	10	μA
Output leakage current	I _{OZ}	V _{CC} = 5.5 V V _{OUT} = 5.5 and GND <u>1/</u> Outputs disabled	1, 2, 3	ALL	-10	10	μA
Output short circuit current	I _{OS}	V _{CC} = 5.5 V, V _{OUT} = GND Unused outputs are open <u>2/ 3/</u>	1, 2, 3	All	-20	-90	mA
Power supply current	I _{CC}	V _{CC} = 5.5 V, 0.0 V ≤ V _{IN} ≤ V _{CC}	1, 2, 3	ALL		120	mA
Input capacitance	C _{IN}	V _{CC} = 5.0 V, f = 1 MHz See 4.3.1c	4	All		10	pF
Output capacitance	C _{OUT}	V _{CC} = 5.0 V, f = 1 MHz See 4.3.1c	4	All		10	pF
Functional tests		See 4.3.1e	7, 8A,8B	All			
Address setup to clock high	t _{SA}	See figure 4 and 5 as applicable	9, 10, 11	01,04	30		ns
				02,05	35		
				03,06	40		
				07	25		
Address hold from clock high	t _{HA}		9, 10, 11	ALL	0		ns
Clock high to output valid	t _{CO}		9, 10, 11	01,04	15		ns
				02,05	20		
				03,06	25		
				07	12		
Clock pulse width	t _{PWC}		9, 10, 11	01,04	15		ns
				02,03, 05,06	20		
				07	10		
\bar{E} s setup to clock high <u>3/</u>	t _{SEs}		9, 10, 11	All	10		ns
\bar{E} s hold from clock HIGH <u>3/</u>	t _{HEs}		9, 10, 11	01-06	5		ns
				07	0		

See footnotes at end of table.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device types	Limits		Unit
					Min	Max	
Output valid from clock high	t _{COS}	See figure 4 and 5 as applicable, <u>3/ 4/</u>	9, 10, 11	01,04,07 02,05 03,06	20 25 30		ns
Output inactive from clock high	t _{HZC}	See figure 4 and 5 as applicable, <u>3/ 4/ 5/</u>	9, 10, 11	01,04,07 02,05 03,06	20 25 30		ns
Output valid from \bar{E} low	t _{DOE}	See figure 4 and 5 as applicable, <u>3/ 6/</u>	9, 10, 11	01,04,07 02,05 03,06	20 25 30		ns
Output inactive from E high	t _{HZE}	See figure 4 and 5 as applicable, <u>3/ 4/ 5/</u>	9, 10, 11	01,04,07 02,05 03,06	20 25 30		ns
Delay from $\overline{\text{PRESET}}$ or $\overline{\text{CLEAR}}$ to valid output	t _{DP} t _{DC}	See figure 4 and 5	9, 10, 11	All	20		ns
$\overline{\text{PRESET}}$ or $\overline{\text{CLEAR}}$ recovery to clock high	t _{RP} t _{RC}	See figure 4 and 5	9, 10, 11	01-06 07	20 15		ns
$\overline{\text{PRESET}}$ or $\overline{\text{CLEAR}}$ pulse width	t _{PWP} t _{PWC}	See figure 4 and 5 <u>3/</u>	9, 10, 11	01-06 07	20 15		ns

1/ For the tests using synchronous enable, the device must be clocked after applying these voltages to perform this measurement.

2/ For test purposes, not more than one output at a time should be shorted. Short circuit test duration should not exceed 30 seconds.

3/ Tested initially and after any design or process changes that affect that parameter, and therefore shall be guaranteed to the limits specified in table I.

4/ Applies only when the synchronous (\bar{E} s) function is used.

5/ Transition is measured at steady state high level -500 mV or steady state low level +500 mV on the output from the 1.5 V level on the input with loads shown on figure 4; C_L = 5 pF.

6/ Applies only when the asynchronous (E) function is used.

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Device types	ALL	
Case outlines	L	3
Terminal number	Terminal symbol	
1	A ₇	NC
2	A ₆	A ₇
3	A ₅	A ₆
4	A ₄	A ₅
5	A ₃	A ₄
6	A ₂	A ₃
7	A ₁	A ₂
8	A ₀	A ₁
9	O ₀	A ₀
10	O ₁	NC
11	O ₂	O ₀
12	GND	O ₁
13	O ₃	O ₂
14	O ₄	GND
15	O ₅	NC
16	O ₆	O ₃
17	O ₇	O ₄
18	$\overline{\text{PGM}} \text{ (CP)}$	O ₅
19	$\overline{\text{VFY}} \text{ (Es)}$	O ₆
20	$\overline{V_{PP}} \text{ (CLR)}$	O ₇
21	$\overline{\text{E}}$	NC
22	$\overline{\text{PS}}$	$\overline{\text{PGM}} \text{ (CP)}$
23	A ₈	$\overline{\text{VFY}} \text{ (Es)}$
24	V _{CC}	$\overline{\text{CLR}}$
25	---	$\overline{\text{E}}$
26	---	$\overline{\text{PS}}$
27	---	A ₈
28	---	V _{CC}

NC = no connection

FIGURE 1. Terminal connections.

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Mode	Read or output disable	CP	E	CLR	E	PS	Outputs
	Other	PGM	V _{VFY}	V _{PP}	E	PS	
Read <u>1/ 2/ 3/</u>	X	X	V _{IL}	V _{IH}	V _{IL}	V _{IH}	Data out
Output disable <u>1/ 4/</u>	X	X	V _{IH}	V _{IH}	X	V _{IH}	High Z
Output disable <u>1/</u>	X	X	X	V _{IH}	V _{IH}	V _{IH}	High Z
CLEAR <u>1/</u>	X	X	V _{IL}	V _{IL}	V _{IL}	V _{IH}	Zeros
PRESET <u>1/</u>	X	X	V _{IL}	V _{IH}	V _{IL}	V _{IL}	Ones

- 1/ X = don't care, but not to exceed V_{PP} = 13.0 V, maximum.
- 2/ During read operation, the output latches are loaded on a "0" to "1" transition of CP.
- 3/ Pin Es must be LOW prior to the "0" to "1" transition on CP that loads the register.
- 4/ Es must be HIGH prior to the "0" to "1" transition on CP that loads the register.

FIGURE 2. Truth table.

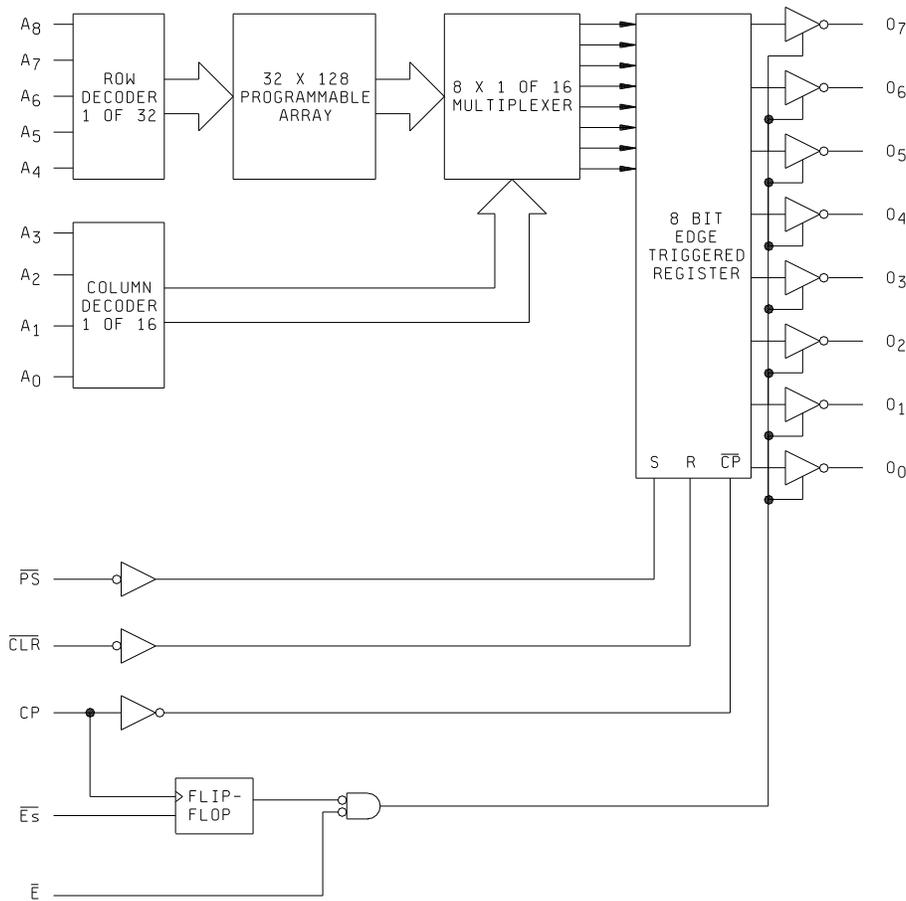
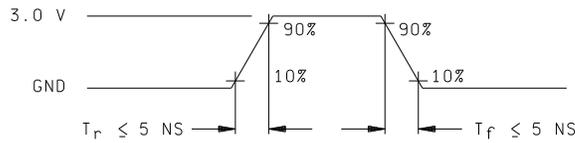
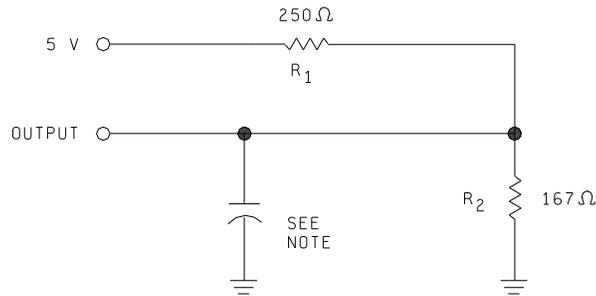


FIGURE 3. Logic diagram

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ALL INPUT PULSES



NOTES:

1. C_L includes probe and jig capacitance. $C_L = 50$ pF for all switching characteristics except t_{HZC} and t_{HZE} . $C_L = 5$ pF for t_{HZC} and t_{HZE} .
2. Tests are performed with rise and fall times of 5 ns or less.
3. All device test loads should be located within two inches of device outputs.

FIGURE 4. Output load circuit and test conditions.

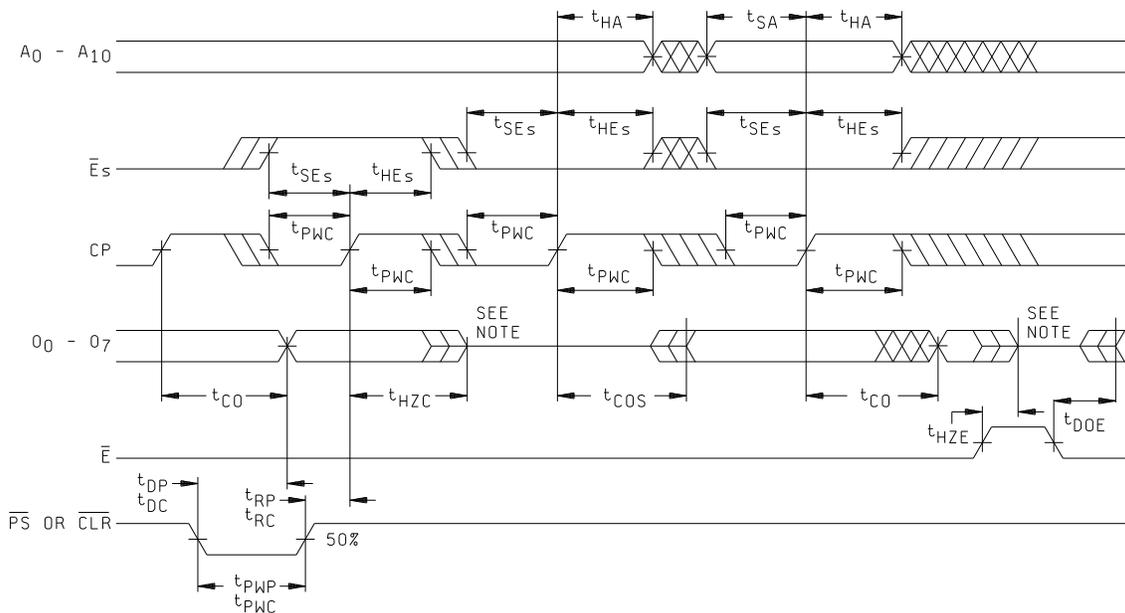


FIGURE 5. Switching waveforms.

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TABLE II. Electrical test requirements. 1/ 2/ 3/ 4/

MIL-STD-883 test requirements	Subgroups (in accordance with method 5005, table I)
Interim electrical parameters (method 5004)	---
Final electrical test parameters (method 5004)	1*, 2, 3, 7*, 8A, 8B, 9, 10, 11
Group A test requirements (method 5005)	1, 2, 3, 4**, 7, 8A, 8B, 9, 10, 11
Groups C and D end-point electrical parameters (method 5005)	2, 3, 7, 8A, 8B

- 1/ * Indicates PDA applies to subgroups 1 and 7.
 2/ Any or all subgroups may be combined when using
 high-speed testers.
 3/ ** See 4.3.1c.
 4/ As a minimum, subgroups 7 and 8 shall consist of verifying
 the data pattern.

4.3.1 Group A inspection.

- a. Tests shall be as specified in table IIA herein.
- b. Subgroups 5 and 6 of table I of method 5005 of MIL-STD-883 shall be omitted.
- c. Subgroup 4 (C_{IN} and C_{OUT} measurement) shall be measured only for the initial test and after process or design changes which may affect capacitance. Sample size is 15 devices with no failures, and all input and output terminals tested.
- d. Unprogrammed devices shall be tested for programmability and ac performance compliance to the requirements of group A, subgroups 9, 10, and 11. Either of two techniques is acceptable:
 - (1) Testing the entire lot using additional built-in test circuitry which allows the manufacturer to verify programmability and ac performance without programming the user array. If this is done, the resulting test patterns shall be verified on all devices during subgroups 9, 10, and 11, group A testing in accordance with the sampling plan specified in MIL-STD-883, method 5005.
 - (2) If such compliance cannot be tested on an unprogrammed device, a sample shall be selected to satisfy programmability requirements prior to performing subgroups 9, 10, and 11. Twelve devices shall be submitted to programming (see 3.2.2.2). If more than two devices fail to program, the lot shall be rejected. At the manufacturer's option, the sample may be increased to 24 total devices with no more than 4 total device failures allowable. Ten devices from the programmability sample shall be submitted to the requirements of group A, subgroups 9, 10, and 11. If more than two devices fail, the lot shall be rejected. At the manufacturer's option, the sample may be increased to 20 total devices with no more than 4 total device failures allowable.
- e. Subgroups 7 and 8 shall include verification of the truth table.

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4.3.2 Groups C and D inspections.

- a. End-point electrical parameters shall be as specified in table II herein.
- b. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883.
 - (2) $T_A = +125^\circ\text{C}$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.
- c. Group C, subgroup 1 sample shall include devices tested in accordance with 4.3.1d.

4.4 Programming procedure. The programming procedures shall be as specified by the device manufacturer and shall be made available upon request.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-STD-883 (see 3.1 herein).

6. NOTES

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.3 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-973 using DD Form 1692, Engineering Change Proposal.

6.4 Record of users. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and the applicable SMD. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronics devices (FSC 5962) should contact DESC-EC, telephone (513) 296-6047.

6.5 Comments. Comments on this drawing should be directed to DESC-EC, Dayton, Ohio 45444-5270, or telephone (513) 296-5377.

6.6 Approved sources of supply. Approved sources of supply are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-EC.

STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	SIZE A		5962-88518
		REVISION LEVEL B	SHEET 11

STANDARDIZED MILITARY DRAWING SOURCE APPROVAL BULLETIN

DATE: 94-04-15

Approved sources of supply for SMD 5962-88518 are listed below for immediate acquisition only and shall be added to MIL-BUL-103 during the next revision. MIL-BUL-103 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DESC-EC. This bulletin is superseded by the next dated revision of MIL-BUL-103.

Standardized Military drawing PIN	Vendor CAGE number	Vendor similar PIN <u>1/</u>
5962-8851801LX	65786	CY7C225-30DMB
5962-88518013X	65786	CY7C225-30LMB
5962-8851802LX	65786	CY7C225-35DMB
5962-88518023X	65786	CY7C225-35LMB
5962-8851803LX	65786	CY7C225-40DMB
5962-88518033X	65786	CY7C225-40LMB
5962-8851804LX	65786	CY7C225A-30DMB
5962-88518043X	65786	CY7C225A-30LMB
5962-8851805LX	65786	CY7C225A-35DMB
5962-88518053X	65786	CY7C225A-35LMB
5962-8851806LX	65786	CY7C225A-40DMB
5962-88518063X	65786	CY7C225A-40LMB
5962-8851807LX	65786	CY7C225A-25DMB
5962-88518073X	65786	CY7C225A-25LMB

1/ Caution. Do not use this number for item acquisition.
Items acquired to this number may not satisfy
the performance requirements of this drawing.

STANDARDIZED MILITARY DRAWING SOURCE APPROVAL BULLETIN - Continued.

Vendor CAGE
number

65786

Vendor name
and address

Cypress Semiconductor
3901 North First Street
San Jose, CA 95134-1599

The information contained herein is disseminated for convenience only and the Government assumes no liability whatsoever for any inaccuracies in this information bulletin.